

描述 / Descriptions

SOT-23 塑封封装 硅半导体二极管。

Silicon Diode in a SOT-23 Plastic Package.

特征 / Features

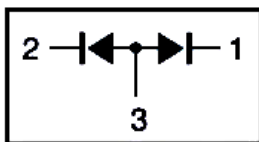
封装小，双二极管，开关速度快，反向峰值电压高，正向电流高达 450mA。

Small package, double diode, high switching speed, high repetitive peak reverse voltage, repetitive peak forward current up to 450mA.

用途 / Applications

主要用于高速开关电路。

High-speed switching in thick and thin-film circuits..

内部等效电路 / Equivalent Circuit**引脚排列 / Pinning**

PIN: See Equivalent Circuit.

放大及印章代码 / h_{FE} Classifications & Marking

Marking	HA1
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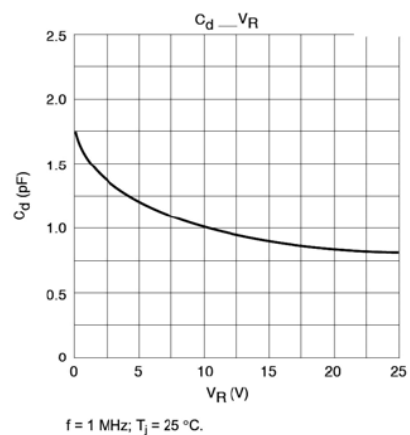
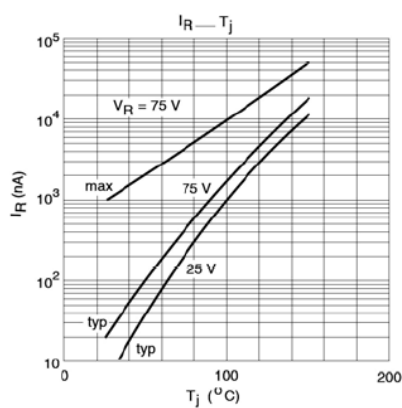
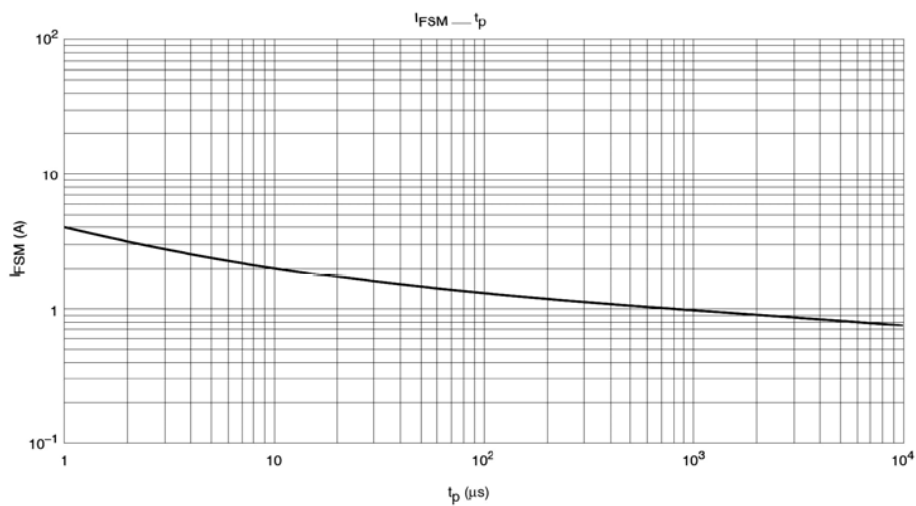
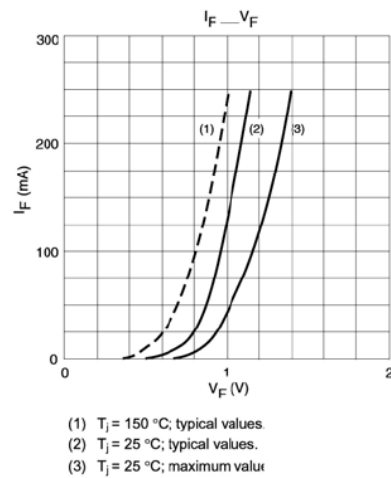
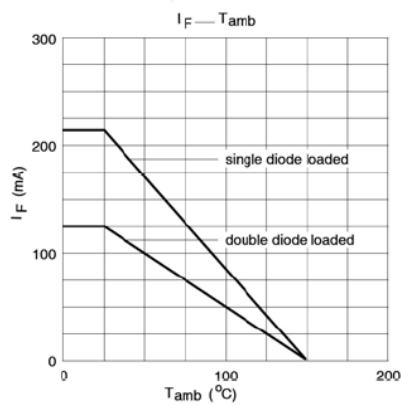
极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Repetitive Reverse Voltage	V_{RRM}	85	V
Continuous Reverse Voltage	V_R	75	V
Average Rectified Forward Current	$I_F(\text{single diode loaded})$	215	mA
	$I_F(\text{double diode loaded})$	125	mA
Repetitive Peak Forward Current	I_{FRM}	450	mA
Non-repetitive Peak Forward Surge Current	$I_{FSM(1)}(t=1\mu S)$	4.0	A
	$I_{FSM(2)}(t=1mS)$	1.0	A
	$I_{FSM(3)}(t=1S)$	0.5	A
Power Dissipation	P_{tot}	250	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Forward Voltage	V_F	$I_F=1.0mA$			715	mV
		$I_F=10mA$			855	mV
		$I_F=50mA$			1.0	V
		$I_F=150mA$			1.25	V
Instantaneous Reverse Current	I_R	$V_R=25V$			30	nA
		$V_R=75V$			1.0	μA
		$V_R=25V \quad T_A=150^\circ C$			30	μA
		$V_R=75V \quad T_A=150^\circ C$			50	μA
Total Capacitance	C_T	$V_R=0 \quad f=1.0MHz$			2.0	pF
Reverse Recovery Time	t_{rr}	$I_F=I_R=10mA$ $I_{RR}=1.0mA \quad R_L=100\Omega$			4.0	ns
Forward recovery voltage	V_{ft}	$I_F=10mA \quad t_i=20ns$			1.75	V

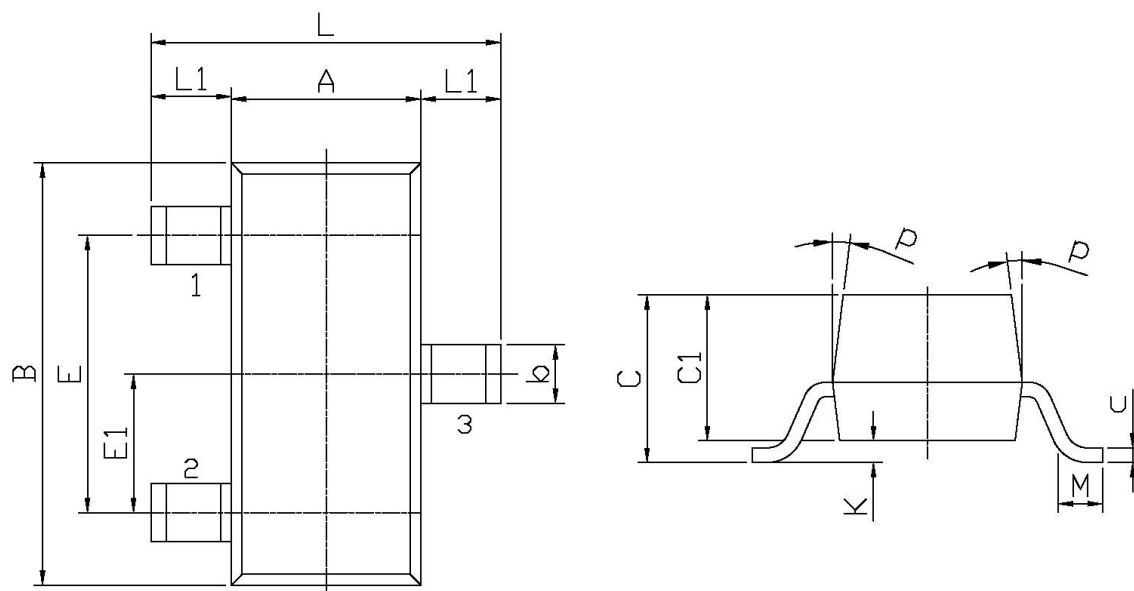
电参数曲线图 / Electrical Characteristic Curve



外形尺寸图 / Package Dimensions

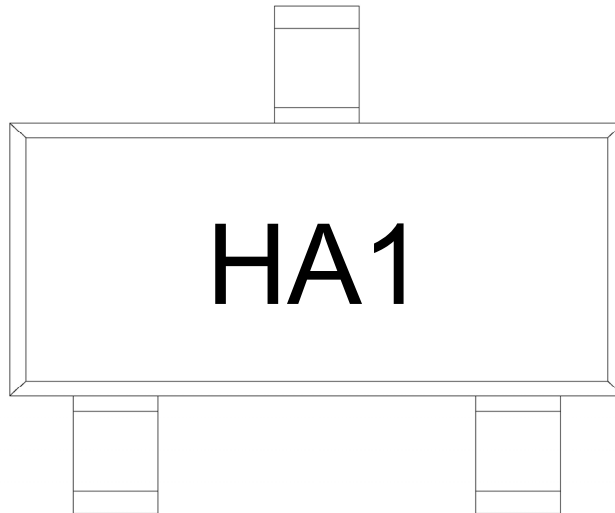
SOT-23

单位: mm



Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
L	2.2	2.7	C	1.30Max	
L1	0.45	0.65	C1	0.90	1.20
A	1.15	1.50	c	0.05	0.20
B	2.70	3.10	K	0	0.10
E	1.70	2.10	M	0.20MIN	
E1	0.85	1.05	P	7°	
b	0.35	0.55			

印章说明 / Marking Instructions



说明：

H： 为公司代码

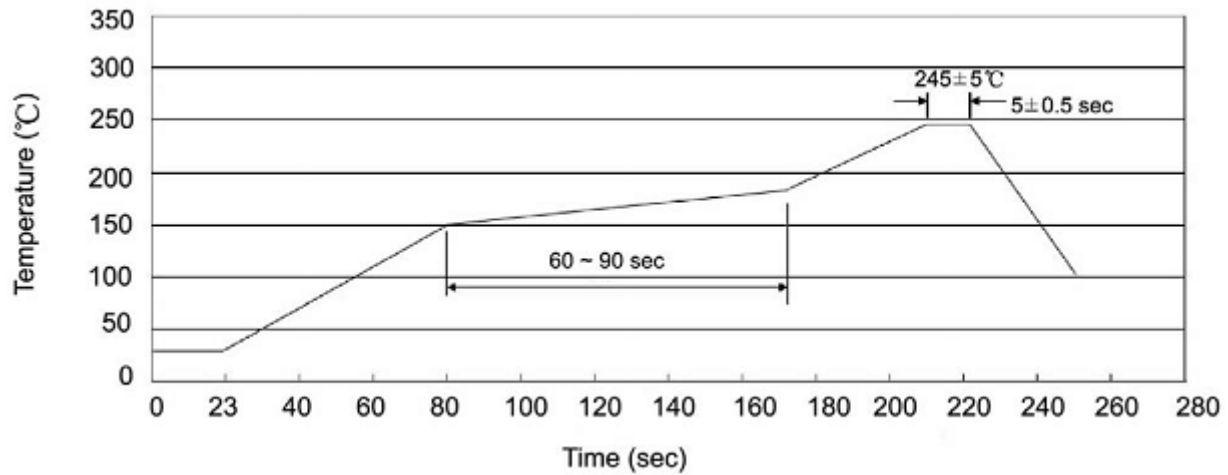
A1： 为型号代码

Note:

H: Company Code.

A1: Product Type.

回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)



说明：

- 1、预热温度 25 ~ 150°C，时间 60 ~ 90sec;
- 2、峰值温度 245±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：260±5°C

时间：10±1 sec.

Temp.:260±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	6	180,000	7" x8	180×120×180	390×385×205

使用说明 / Notices